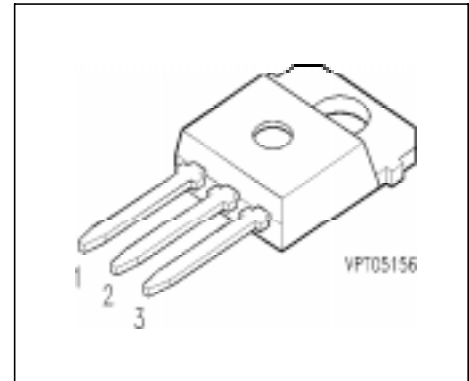


IGBT With Antiparallel Diode

Preliminary data

- Low forward voltage drop
- High switching speed
- Low tail current
- Latch-up free
- Including fast free-wheel diode



Pin 1	Pin 2	Pin 3
G	C	E

Type	V_{CE}	I_C	Package	Ordering Code
BUP 306D	1200V	23A	TO-218 AB	Q67040-A4222-A2

Maximum Ratings

Parameter	Symbol	Values	Unit
Collector-emitter voltage	V_{CE}	1200	V
Collector-gate voltage $R_{GE} = 20 \text{ k}\Omega$	V_{CGR}	1200	
Gate-emitter voltage	V_{GE}	± 20	
DC collector current $T_C = 25 \text{ }^\circ\text{C}$ $T_C = 90 \text{ }^\circ\text{C}$	I_C	23 15	A
Pulsed collector current, $t_p = 1 \text{ ms}$ $T_C = 25 \text{ }^\circ\text{C}$ $T_C = 90 \text{ }^\circ\text{C}$	I_{Cpuls}	46 30	
Diode forward current $T_C = 90 \text{ }^\circ\text{C}$	I_F	18	
Pulsed diode current, $t_p = 1 \text{ ms}$ $T_C = 25 \text{ }^\circ\text{C}$	I_{Fpuls}	108	
Power dissipation $T_C = 25 \text{ }^\circ\text{C}$	P_{tot}	165	W
Chip or operating temperature	T_j	-55 ... + 150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 ... + 150	

Maximum Ratings

Parameter	Symbol	Values	Unit
DIN humidity category, DIN 40 040	-	E	-
IEC climatic category, DIN IEC 68-1	-	55 / 150 / 56	

Thermal Resistance

Thermal resistance, chip case	R_{thJC}	0.63	K/W
Diode thermal resistance, chip case	R_{thJcD}	1.25	

Electrical Characteristics, at $T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

Static Characteristics

Gate threshold voltage $V_{GE} = V_{CE}, I_C = 0.7\text{ mA}$	$V_{GE(th)}$	4.5	5.5	6.5	V
Collector-emitter saturation voltage $V_{GE} = 15\text{ V}, I_C = 10\text{ A}, T_j = 25\text{ °C}$ $V_{GE} = 15\text{ V}, I_C = 10\text{ A}, T_j = 125\text{ °C}$	$V_{CE(sat)}$	-	2.8	3.3	
Zero gate voltage collector current $V_{CE} = 1200\text{ V}, V_{GE} = 0\text{ V}, T_j = 25\text{ °C}$	I_{CES}	-	-	0.4	mA
Gate-emitter leakage current $V_{GE} = 20\text{ V}, V_{CE} = 0\text{ V}$	I_{GES}	-	-	100	nA

AC Characteristics

Transconductance $V_{CE} = 20\text{ V}, I_C = 10\text{ A}$	g_{fs}	3.5	5.5	-	S
Input capacitance $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$	C_{iss}	-	1300	1750	pF
Output capacitance $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$	C_{oss}	-	100	150	
Reverse transfer capacitance $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$	C_{rss}	-	50	75	

Electrical Characteristics, at $T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

Switching Characteristics, Inductive Load at $T_j = 125\text{ °C}$

Turn-on delay time $V_{CC} = 600\text{ V}$, $V_{GE} = 15\text{ V}$, $I_C = 10\text{ A}$ $R_{Gon} = 47\ \Omega$	$t_{d(on)}$	-	40	60	ns
Rise time $V_{CC} = 600\text{ V}$, $V_{GE} = 15\text{ V}$, $I_C = 10\text{ A}$ $R_{Gon} = 47\ \Omega$	t_r	-	30	50	
Turn-off delay time $V_{CC} = 600\text{ V}$, $V_{GE} = -15\text{ V}$, $I_C = 10\text{ A}$ $R_{Goff} = 47\ \Omega$	$t_{d(off)}$	-	200	300	
Fall time $V_{CC} = 600\text{ V}$, $V_{GE} = -15\text{ V}$, $I_C = 10\text{ A}$ $R_{Goff} = 47\ \Omega$	t_f	-	20	30	
Total turn-off loss energy $V_{CC} = 600\text{ V}$, $V_{GE} = -15\text{ V}$, $I_C = 10\text{ A}$ $R_{Goff} = 47\ \Omega$	E_{off}	-	1.3	-	mWs

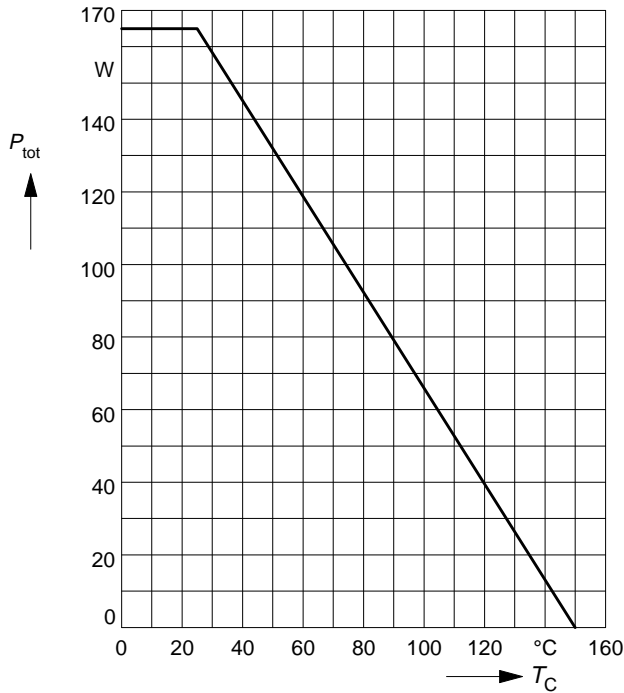
Free-Wheel Diode

Diode forward voltage $I_F = 15\text{ A}$, $V_{GE} = 0\text{ V}$, $T_j = 25\text{ °C}$ $I_F = 15\text{ A}$, $V_{GE} = 0\text{ V}$, $T_j = 125\text{ °C}$	V_F	-	2.4	2.9	V
		-	1.9	-	
Reverse recovery time $I_F = 15\text{ A}$, $V_R = -600\text{ V}$, $V_{GE} = 0\text{ V}$ $di_F/dt = -800\text{ A}/\mu\text{s}$ $T_j = 25\text{ °C}$ $T_j = 125\text{ °C}$	t_{rr}	-	-	-	ns
		-	100	150	
Reverse recovery charge $I_F = 15\text{ A}$, $V_R = 0\text{ V}$, $di_F/dt = -800\text{ A}/\mu\text{s}$ $I_F = 15\text{ A}$, $V_{GE} = 0\text{ V}$, $T_j = 25\text{ °C}$ $V_R = 0\text{ V}$, $di_F/dt = -800\text{ A}/\mu\text{s}$, $T_j = 125\text{ °C}$	Q_{rr}	-	1	1.8	μC
		-	3	5.4	

Power dissipation

$$P_{\text{tot}} = f(T_C)$$

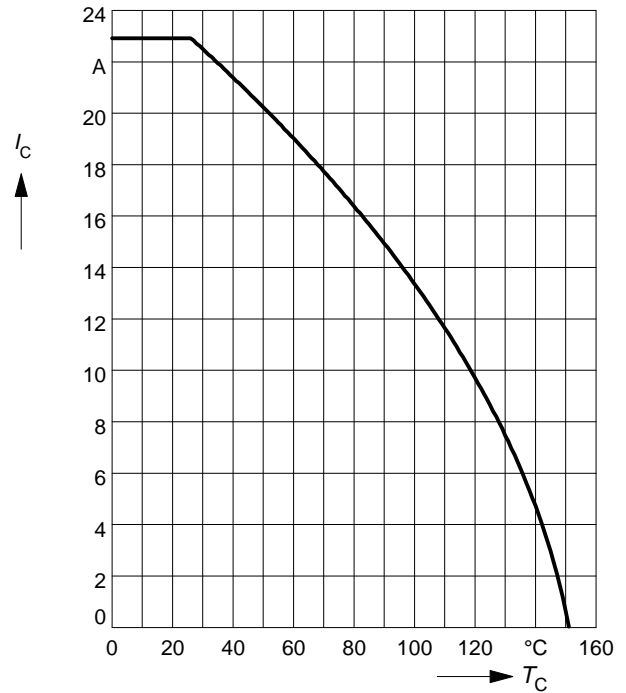
parameter: $T_j \leq 150^\circ\text{C}$



Collector current

$$I_C = f(T_C)$$

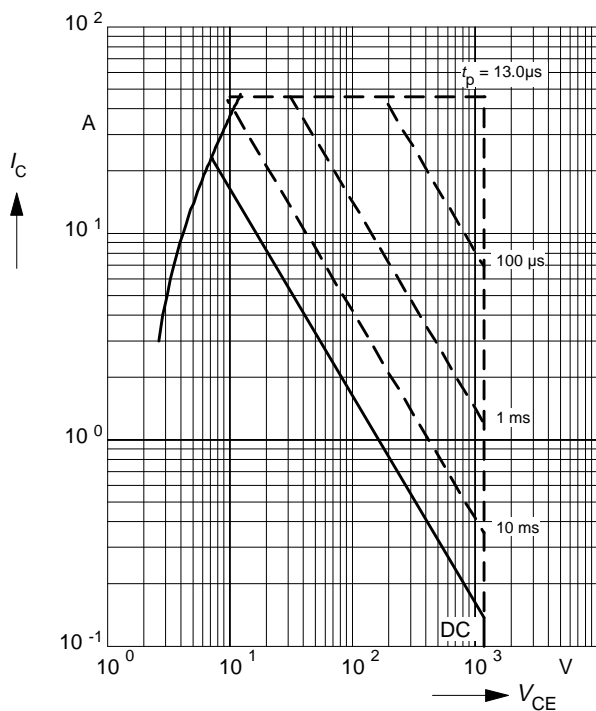
parameter: $V_{\text{GE}} \geq 15\text{ V}$, $T_j \leq 150^\circ\text{C}$



Safe operating area

$$I_C = f(V_{\text{CE}})$$

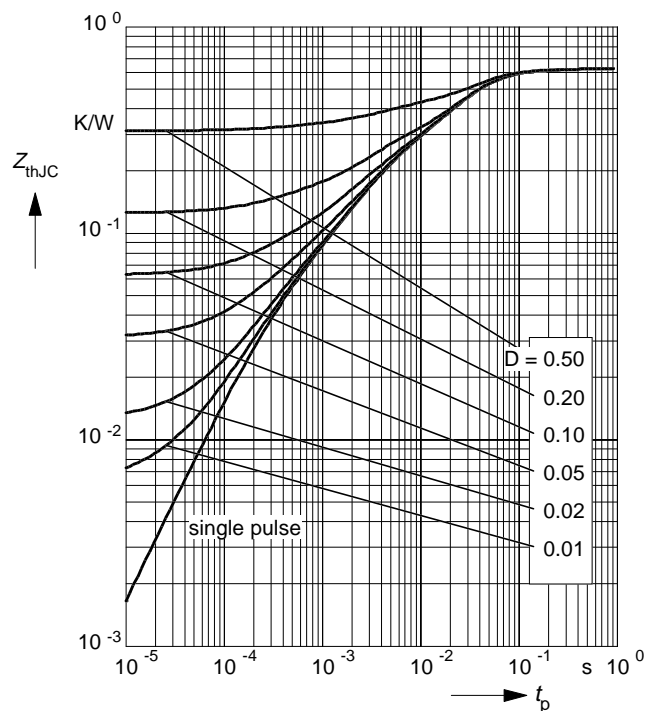
parameter: $D = 0$, $T_C = 25^\circ\text{C}$, $T_j \leq 150^\circ\text{C}$



Transient thermal impedance IGBT

$$Z_{\text{thJC}} = f(t_p)$$

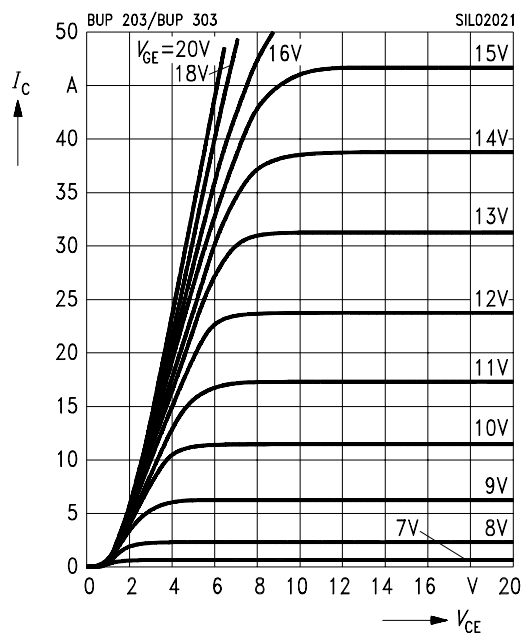
parameter: $D = t_p / T$



Typ. output characteristics

$$I_C = f(V_{CE})$$

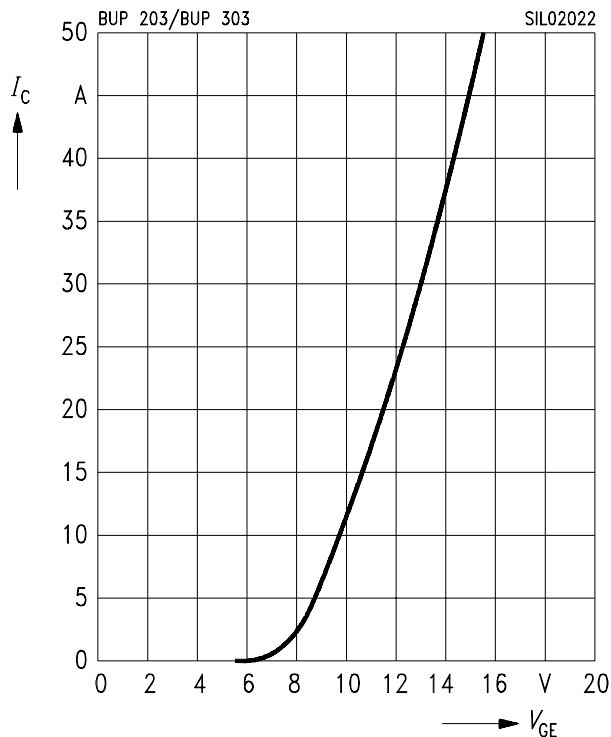
parameter: $t_p = 80 \mu s$, $T_j = 125 \text{ }^\circ\text{C}$



Typ. transfer characteristics

$$I_C = f(V_{GE})$$

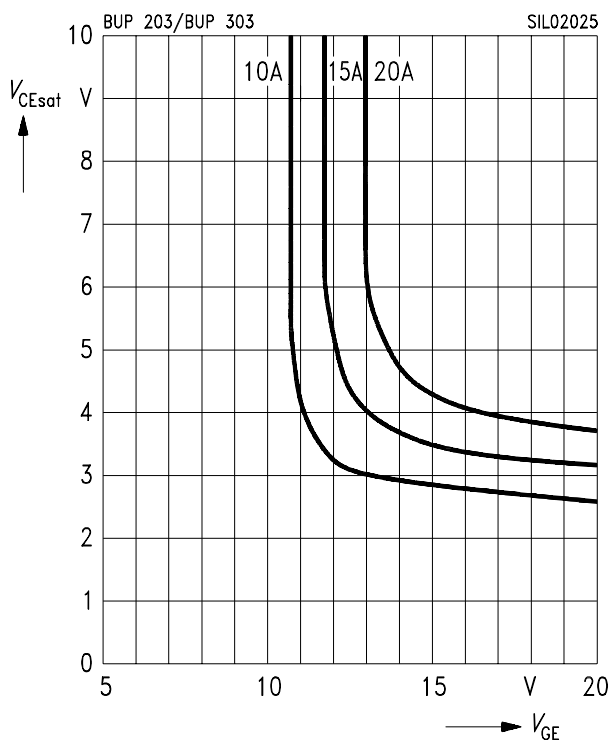
parameter: $t_p = 80 \mu s$, $V_{CE} = 20 \text{ V}$, $T_j = 25 \text{ }^\circ\text{C}$



Typ. saturation characteristics

$$V_{CE(sat)} = f(V_{GE})$$

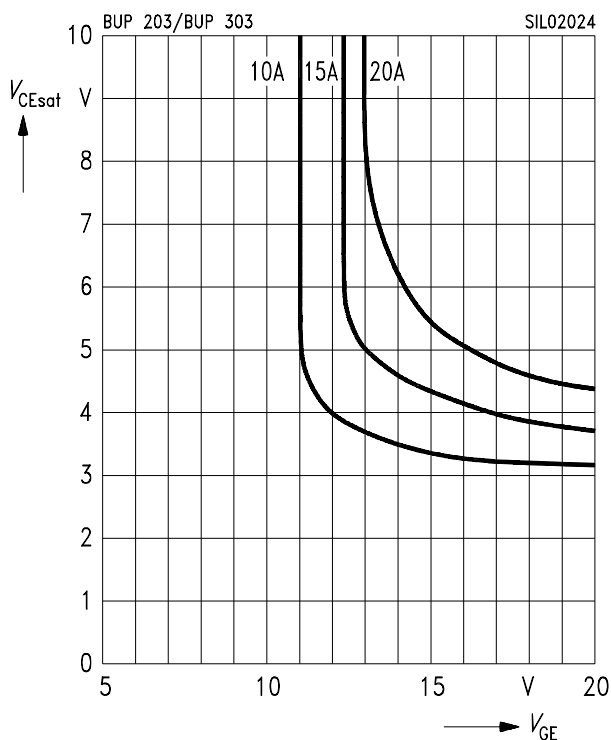
parameter: $T_j = 25 \text{ }^\circ\text{C}$



Typ. saturation characteristics

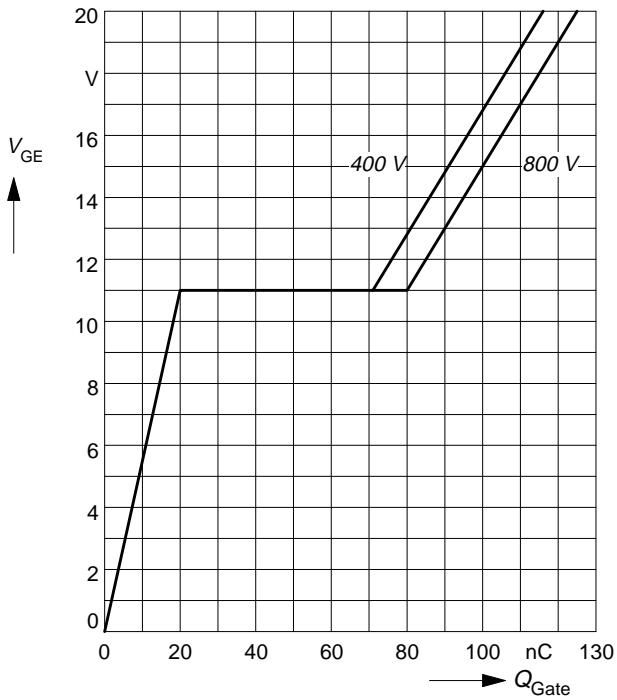
$$V_{CE(sat)} = f(V_{GE})$$

parameter: $T_j = 125 \text{ }^\circ\text{C}$



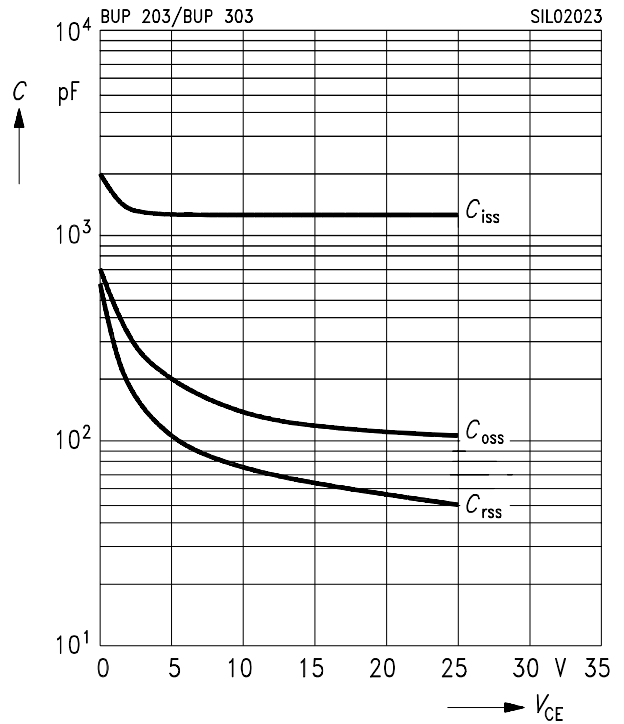
Typ. gate charge

$V_{GE} = f(Q_{Gate})$
 parameter: $I_{C\ puls} = 10\ A$



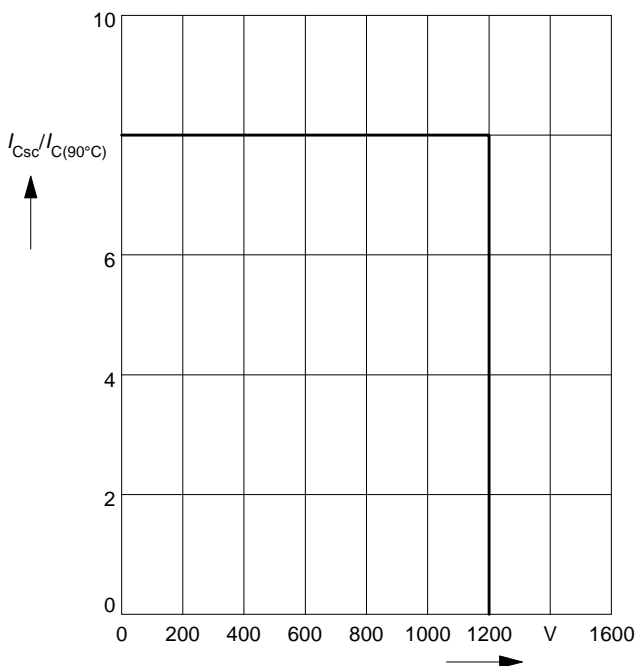
Typ. capacitances

$C = f(V_{CE})$
 parameter: $V_{GE} = 0\ V, f = 1\ MHz$



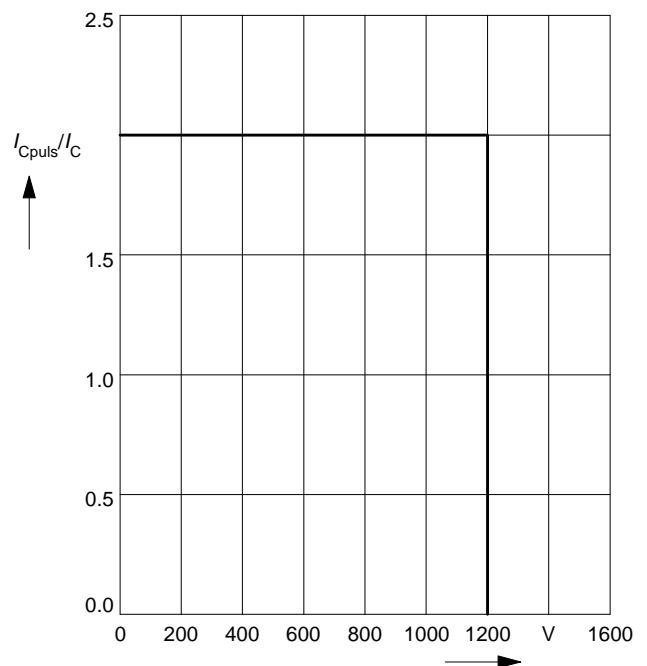
Short circuit safe operating area

$I_{Csc} = f(V_{CE}), T_j = 150^\circ C$
 parameter: $V_{GE} = \pm 15\ V, t_{sc} \leq 10\ \mu s, L < 25\ nH$



Reverse biased safe operating area

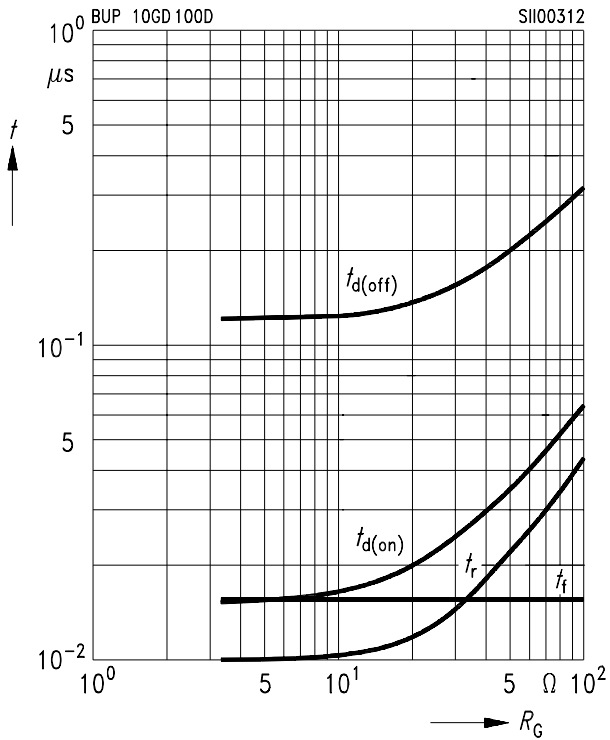
$I_{Cpuls} = f(V_{CE}), T_j = 150^\circ C$
 parameter: $V_{GE} = 15\ V$



Typ. switching time

$t = f(R_G)$, inductive load, $T_j = 125\text{ }^\circ\text{C}$

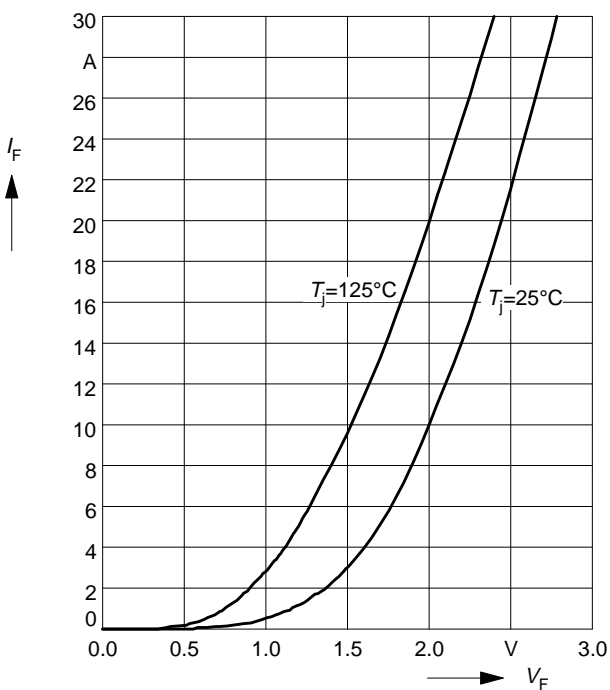
parameter: $V_{CE} = 600\text{ V}$, $V_{GE} = \pm 15\text{ V}$, $I_C = 10\text{ A}$



Typ. forward characteristics

$I_F = f(V_F)$

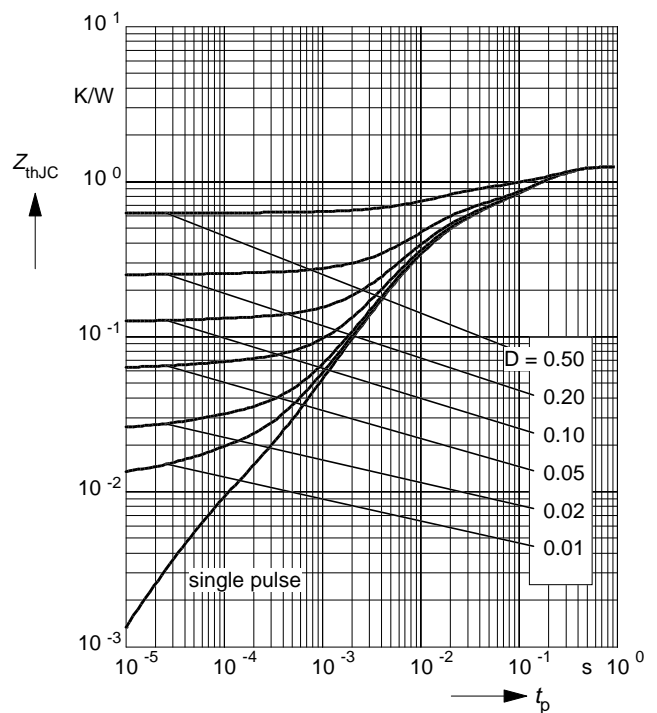
parameter: T_j



Transient thermal impedance Diode

$Z_{th\text{JC}} = f(t_p)$

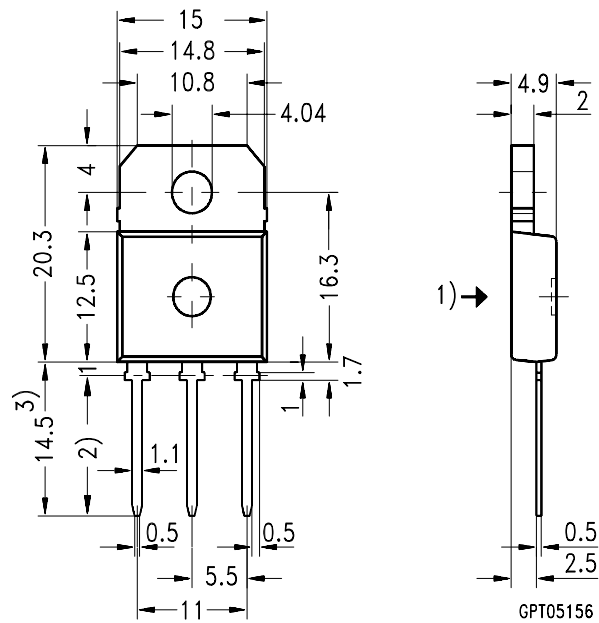
parameter: $D = t_p / T$



Package Outlines

Dimensions in mm

Weight:



- 1) punch direction, burr max. 0.04
- 2) dip finning
- 3) max. 15.5 by dip finning press burr max. 0.05



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